LM110/LM210/LM310 Voltage Follower

General Description

The LM110 series are monolithic operational amplifiers internally connected as unity-gain non-inverting amplifiers. They use super-gain transistors in the input stage to get low bias current without sacrificing speed. Directly interchangeable with 101, 741 and 709 in voltage follower applications. these devices have internal frequency compensation and provision for offset balancing.

The LM110 series are useful in fast sample and hold circuits, active filters, or as general-purpose buffers. Further, the frequency response is sufficiently better than standard IC amplifiers that the followers can be included in the feedback loop without introducing instability. They are plug-in replacements for the LM102 series voltage followers, offering lower offset voltage, drift, bias current and noise in addition to higher speed and wider operating voltage range.

The LM110 is specified over a temperature range -55°C ≤ $T_A \le +125$ °C, the LM210 from -25°C $\le T_A \le +85$ °C and the LM310 from $0^{\circ}C \leq T_{A} \leq +70^{\circ}C$.

Features

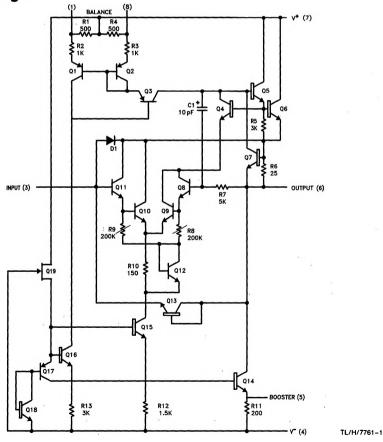
- Input current
- 10 nA max over temperature
- Small signal bandwidth

20 MHz

■ Slew rate ■ Supply voltage range

30 V/us ±5V to ±18V

Schematic Diagram



Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications. (Note 6)

 Storage Temperature Range -65°C to +150°C
Lead Temperature (Soldering, 10 sec.) 260°C
Soldering Information
Dual-In-Line Package
Soldering (10 sec.) 260°C
Small Outline Package
Vapor Phase (60 sec.) 215°C
Infrared (15 sec.) 220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

ESD rating to be determined.

Electrical Characteristics (Note 4)

Parameter	Conditions	LM110			LM210			LM310			Units
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Onics
Input Offset Voltage	T _A = 25°C		1.5	4.0		1.5	4.0		2.5	7.5	mV
Input Bias Current	T _A = 25°C		1.0	3.0		1.0	3.0		2.0	7.0	nA
Input Resistance	T _A = 25°C	1010	1012		1010	1012		1010	1012		Ω
Input Capacitance			1.5			1.5			1.5		pF
Large Signal Voltage Gain	$T_A = 25^{\circ}\text{C}, V_S = \pm 15\text{V}$ $V_{\text{OUT}} = \pm 10\text{V}, R_L = 8 \text{ k}\Omega$	0.999	0.9999	-	0.999	0.9999		0.999	0.9999		V/V
Output Resistance	T _A = 25°C		0.75	2.5		0.75	2.5		0.75	2.5	Ω
Supply Current	T _A = 25°C		3.9	5.5	-1-	3.9	5.5		3.9	5.5	mA
Input Offset Voltage				6.0			6.0			10	mV
Offset Voltage Temperature Drift	$-55^{\circ}\text{C} \le T_{A} \le +85^{\circ}\text{C}$ $+85 \le T_{A} \le 125^{\circ}\text{C}$ $0^{\circ}\text{C} \le T_{A} \le +70^{\circ}\text{C}$		6 12			6			10		μV/°C μV/°C μV/°C
Input Bias Current				10			10			10	nA
Large Signal Voltage Gain	$V_S = \pm 15V$, $V_{OUT} = \pm 10V$ $R_L = 10 \text{ k}\Omega$	0.999			0.999			0.999			V/V
Output Voltage Swing (Note 5)	$V_S = \pm 15V$, $R_L = 10 k\Omega$	± 10			±10			±10			٧
Supply Current	T _A = 125°C		2.0	4.0		2.0	4.0				mA
Supply Voltage Rejection Ratio	±5V ≤ V _S ≤ ±18V	70	80		70	80		70	80		dB

Note 1: The maximum junction temperature of the LM110 is 150°C, of the LM210 is 100°C, and of the LM310 is 85°C. For operating at elevated temperatures, devices in the HO8 package must be derated based on a thermal resistance of 165°C/W, junction to ambient, or 22°C/W, junction to case. The thermal resistance of the dual-in-line package is 100°C/W, junction to ambient.

Note 2: For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Note 3: Continuous short circuit for the LM110 and LM210 is allowed for case temperatures to 125°C and ambient temperatures to 70°C, and for the LM310, 70°C case temperature or 55°C ambient temperature. It is necessary to insert a resistor greater than 2 k Ω in series with the input when the amplifier is driven from low impedance sources to prevent damage when the output is shorted. $R_S = 5$ k min, 10k typical is recommended for dynamic stability in all applications.

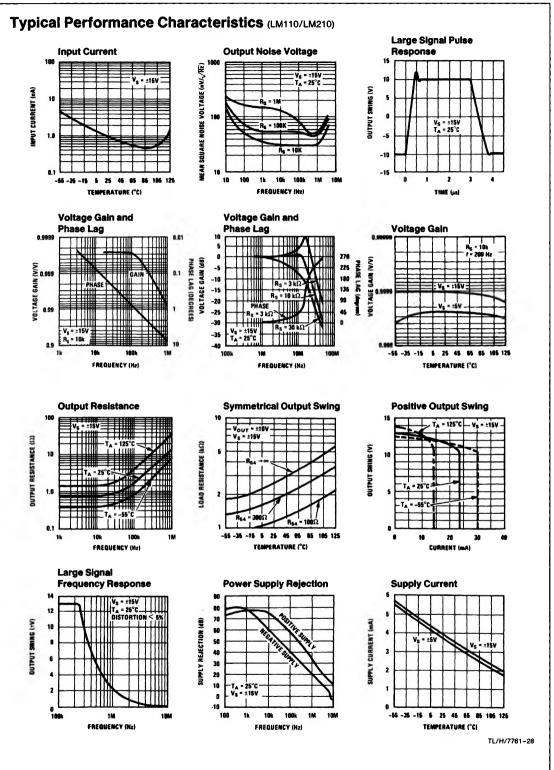
Note 4: These specifications apply for $\pm 5\text{V} \le \text{V}_S \le \pm 18\text{V}$ and $-55^{\circ}\text{C} \le \text{T}_A$ 125°C for the LM110, $-25^{\circ}\text{C} \le \text{T}_A \le 85^{\circ}\text{C}$ for the LM210, and $0^{\circ}\text{C} \le \text{T}_A \le 70^{\circ}\text{C}$ for the LM310 unless otherwise specified.

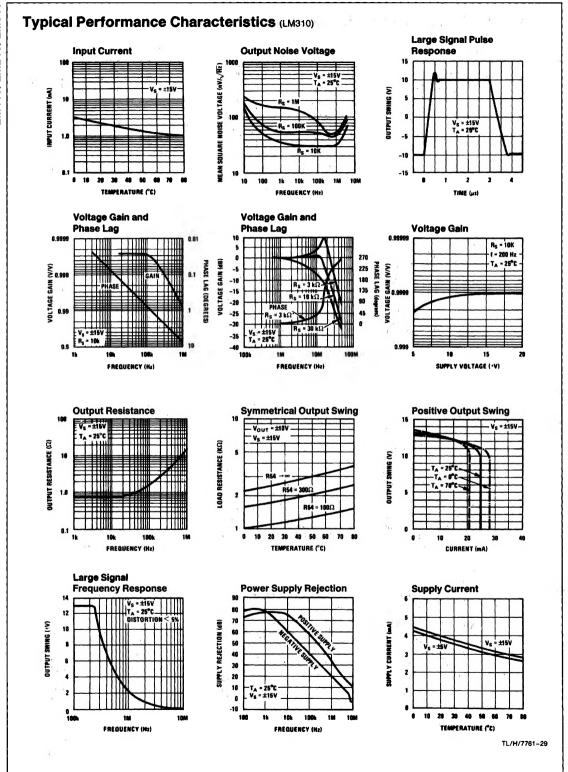
Note 5: Increased output swing under load can be obtained by connecting an external resistor between the booster and V⁻ terminals. See curve.

Note 6: Refer to RETS110X for LM110H, LM110J military specifications.

Application Hint

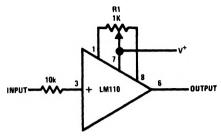
The input must be driven from a source impedance of typically 10 k Ω (5 k Ω min.) to maintain stability. The total source impedance will be reduced at high frequencies if there is stray capacitance at the input pin. In these cases, a 10 k Ω resistor should be inserted in series with the input, physically close to the input pin to minimize the stray capacitance and prevent oscillation.



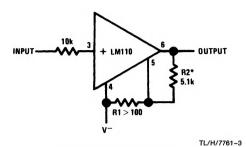


Auxiliary Circuits

Offset Balancing Circuit



Increasing Negative Swing Under Load

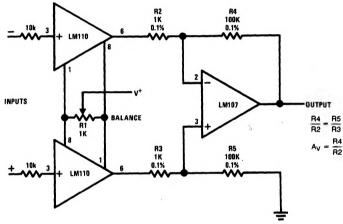


TL/H/7761-2

*May be added to reduce internal dissipation

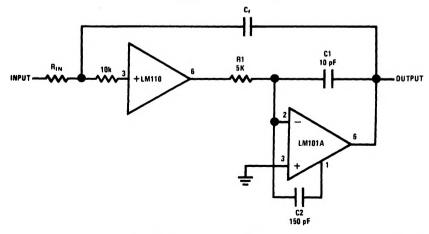
Typical Applications

Differential Input Instrumentation Amplifler

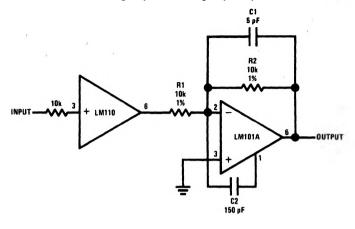


TL/H/7761-4

Fast Integrator with Low Input Current

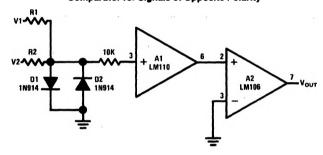


Fast Inverting Amplifier with High Input Impedance



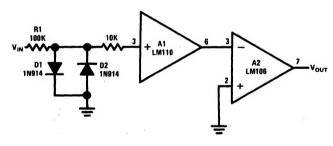
TL/H/7761-6

Comparator for Signals of Opposite Polarity

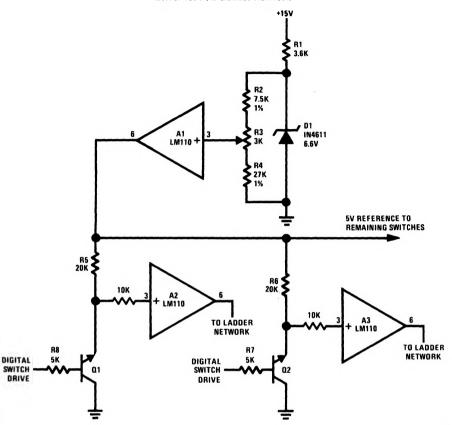


TL/H/7761-7

Zero Crossing Detector

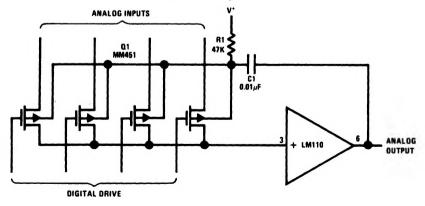


Driver for A/D Ladder Network



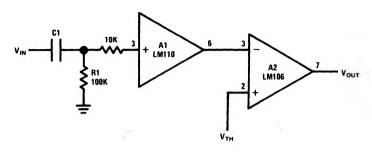
TL/H/7761-8

Buffer for Analog Switch*



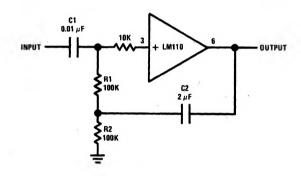
*Switch substrates are boot-strapped to reduce output capacitance of switch.

Comparator for AC Coupled Signals



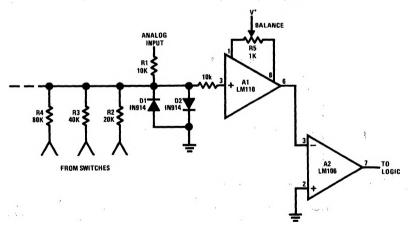
TL/H/7761-11

High Input Impedance AC Amplifier



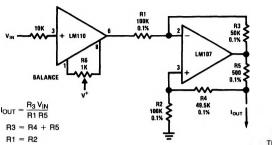
TL/H/7761-12

Comparator for A/D Converter Using a Binary-Weighted Network



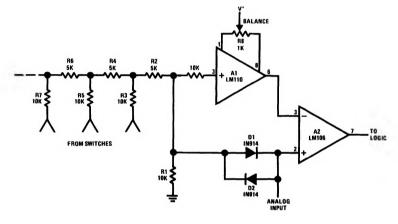
TL/H/7761~13

Bilateral Current Source



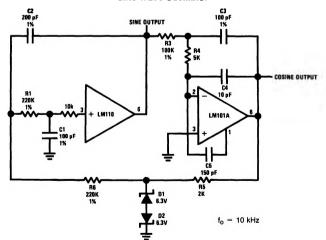
TL/H/7761-14

Comparator for A/D Converter Using a Ladder Network

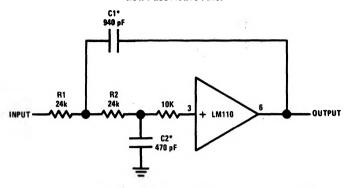


TL/H/7761-15

Sine Wave Oscillator



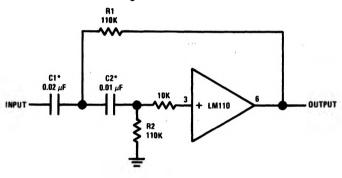
Low Pass Active Filter



TL/H/7761-18

*Values are for 10 kHz cutoff. Use silvered mica capacitors for good temperature stability.

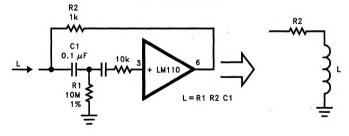
High Pass Active Filter



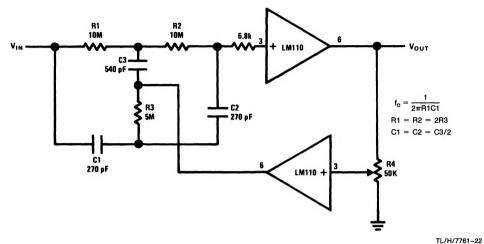
TL/H/7761-19

*Values are for 100 Hz cutoff. Use metalized polycarbonate capacitors for good temperature stability.

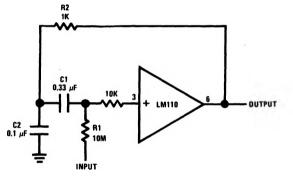
Simulated Inductor



Adjustable Q Notch Filter

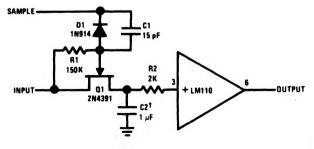


Bandpass Filter



TL/H/7761-23

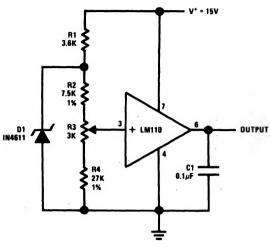
Sample and Hold



TL/H/7761-24

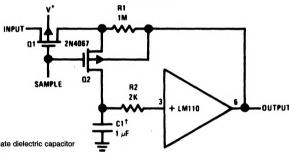
†Use capacitor with polycarbonate teflon or polythylene dietetric

Buffered Reference Source



TL/H/7761-25

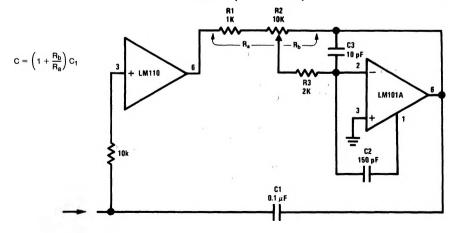
Low Drift Sample and Hold*



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TL/H/7761-26

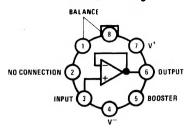
Variable Capacitance Multiplier



^{*}Worst case drift less than 3 mV/sec

Connection Diagrams

Metal Can Package



TL/H/7761-30

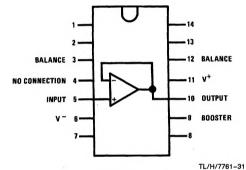
Package is connected to Pin 4 (V⁻)

Top View

Order Number LM110H, LM210H or LM310H LM110H/883*

See NS Package Number H08C

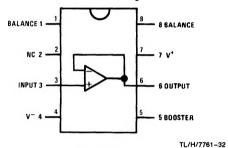
Dual-In-Line Package



Top View

Order Number LM110J, LM210J, LM310J or LM110J/883* See NS Package Number J14A

Dual-In-Line Package



Top View

Order Number LM310M, LM310N or LM110J-8/883* See NS Package Number J08A, M08A or N08E

^{*}Available per SMD # 5962-8760601